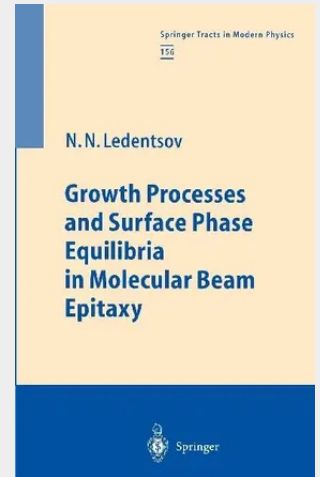


Growth Processes and Surface Phase Equilibria in Molecular Beam Epitaxy

The book considers the main growth-related phenomena occurring during epitaxial growth, such as thermal etching, doping, segregation of the main elements and impurities, coexistence of several phases at the crystal surface and segregation-enhanced diffusion.

It is complete with tables, graphs and figures, which allow fast determination of suitable growth parameters for practical applications.

The book considers the main growth-related phenomena occurring during epitaxial growth, such as thermal etching, doping, segregation of the main elements and impurities, coexistence of several phases at the crystal surface and segregation-enhanced diffusion. It is complete with tables, graphs and figures, which allow fast determination of suitable growth parameters for practical applications.



106,99 €

106,99 € (zzgl. MwSt.)

Lieferfrist: bis zu 10 Tage

Artikelnummer: 9783540657941

Medium: Buch

ISBN: 978-3-540-65794-1

Verlag: Springer Berlin Heidelberg

Erscheinungstermin: 02.07.1999

Sprache(n): Englisch

Auflage: 1. Auflage 1999

Serie: Springer Tracts in Modern Physics

Produktform: Gebunden

Gewicht: 336 g

Seiten: 86

Format (B x H): 160 x 241 mm

